

Plastic-Encapsulate Transistors

TRANSISTOR (PNP)

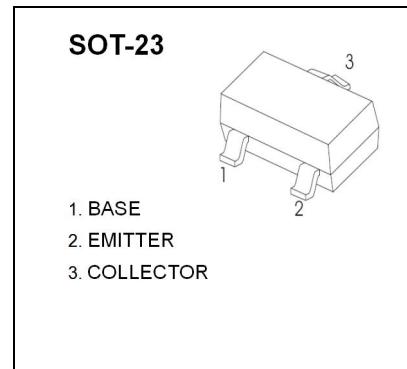
FEATURES

Low equivalent on-resistance

Marking :591

MAXIMUM RATINGS ($T_a=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Value	Unit
V_{CBO}	Collector-Base Voltage	-80	V
V_{CEO}	Collector-Emitter Voltage	-60	V
V_{EBO}	Emitter-Base Voltage	-5	V
I_c	Collector Current	-1	A
I_{CM}	Peak Pulse Current	-2	A
P_c	Collector Power Dissipation	250	mW
$R_{\theta\text{JA}}$	Thermal Resistance From Junction To Ambient	500	°C/W
T_j	Junction Temperature	150	°C
T_{stg}	Storage Temperature	-55~+150	°C

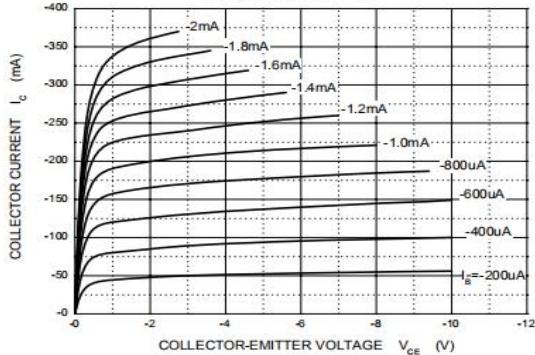


ELECTRICAL CHARACTERISTICS ($T_a=25^\circ\text{C}$ unless otherwise specified)

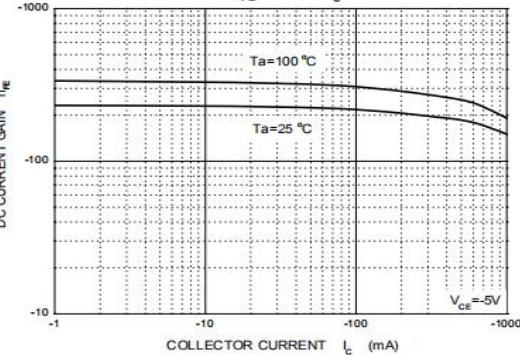
Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	$V_{(\text{BR})\text{CBO}}$	$I_C=-100\mu\text{A}, I_E=0$	-80			V
Collector-emitter breakdown voltage	$V_{(\text{BR})\text{CEO}}$	$I_C=-10\text{mA}, I_B=0$	-60			V
Emitter-base breakdown voltage	$V_{(\text{BR})\text{EBO}}$	$I_E=-100\mu\text{A}, I_C=0$	-5			V
Collector cut-off current	I_{CBO}	$V_{\text{CB}}=-60\text{V}, I_E=0$			-0.1	μA
Emitter cut-off current	I_{EBO}	$V_{\text{EB}}=-4\text{V}, I_C=0$			-0.1	μA
DC current gain	$h_{FE(1)}$	$V_{\text{CE}}=-5\text{V}, I_C=-1\text{mA}$	100			
	$h_{FE(2)}$	$V_{\text{CE}}=-5\text{V}, I_C=-500\text{mA}$	100		300	
	$h_{FE(3)}$	$V_{\text{CE}}=-5\text{V}, I_C=-1\text{A}$	80			
	$h_{FE(4)}$	$V_{\text{CE}}=-5\text{V}, I_C=-2\text{A}$	15			
Collector-emitter saturation voltage	$V_{\text{CE}(\text{sat})1}$	$I_C=-500\text{mA}, I_B=-50\text{mA}$			-0.3	V
	$V_{\text{CE}(\text{sat})2}$	$I_C=-1\text{A}, I_B=-100\text{mA}$			-0.6	V
Base-emitter saturation voltage	$V_{\text{BE}(\text{sat})}$	$I_C=-1\text{A}, I_B=-100\text{mA}$			-1.2	V
Base-emitter voltage	V_{BE}	$V_{\text{CE}}=-5\text{V}, I_C=-1\text{A}$			-1	V
Transition frequency	f_T	$V_{\text{CE}}=-10\text{V}, I_C=-50\text{mA}, f=100\text{MHz}$	150			MHz
Collector output capacitance	C_{ob}	$V_{\text{CB}}=-10\text{V}, f=1\text{MHz}$			10	pF

Typical Characteristics

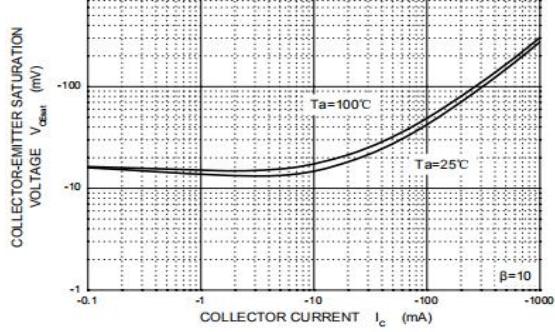
Static Characteristic



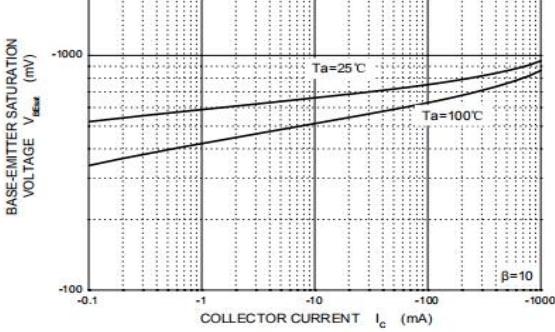
h_{FE} — I_c



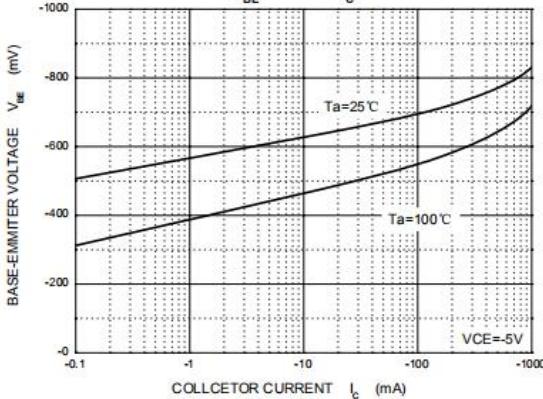
V_{CEsat} — I_c



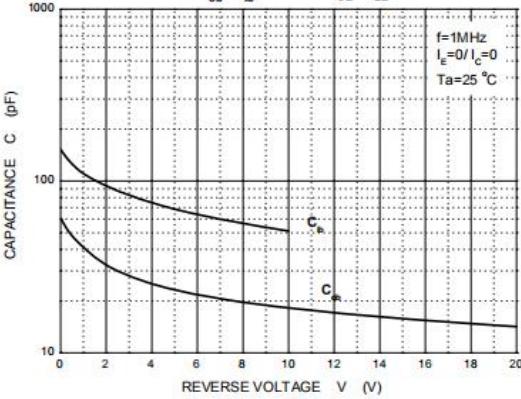
V_{BESAT} — I_c



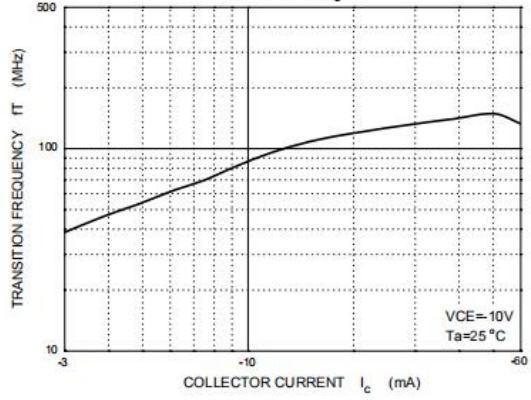
V_{BE} — I_c



C_{ob}/C_{ib} — V_{CB}/V_{EB}



f_T — I_c



P_c — T_a

